SN54F244, SN74F244 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS SDFS063A – D2932, MARCH 1987 – REVISED OCTOBER 1993

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Package Options Include Plastic Small-Outline (SOIC) and Shrink Small-Outline (SSOP) Packages, Ceramic Chip Carriers, and Plastic and Ceramic DIPs

description

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. Taken together with the 'F240 and 'F241, these devices provide the choice of selected combinations of inverting and noninverting outputs, symmetrical \overline{OE} (active-low output-enable) inputs, and complementary OE and \overline{OE} inputs.

The 'F244 is organized as two 4-bit buffers/line drivers with separate output enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

The SN74F244 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54F244 is characterized for operation over the full military temperature range of -55° C to 125°C. The SN74F244 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE					
(each buffer)					
INPUTS	OUTPI				

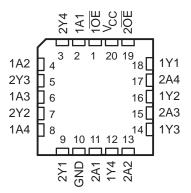
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	JTS	OUTPUT
OE	Α	Y
L	Н	Н
L	L	L
н	Х	Z

SN54F244 J PACKAGE							
SN74F244	. DB, DW, OR N PACKAGE						
	(TOP VIEW)						

	(,	
1 <u>0</u> E [J ₂₀	V _{CC}
1A1 [2Y4]	2	19 18] 2 <u>0</u> E] 1Y1
1A2 [4	17	2A4
2Y3 [5	16] 1Y2
1A3 [6	15	2A3
2Y2 [7	14] 1Y3
1A4 [2Y1]	8 9	13 12	2A2
GND [10	12] 2A1
	-		

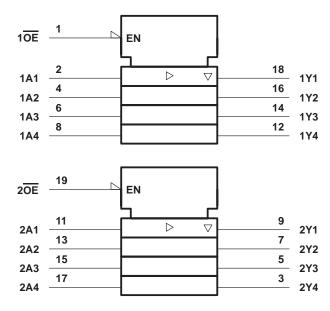
SN54F244 . . . FK PACKAGE (TOP VIEW)



SN54F244, SN74F244 **OCTAL BUFFERS/DRIVERS** WITH 3-STATE OUTPUTS

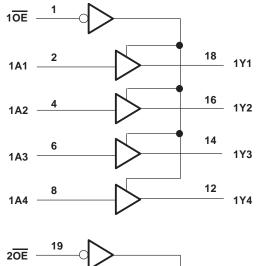
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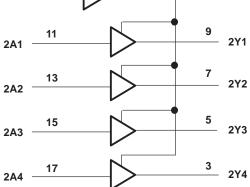
logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage range, V _{CC} Input voltage range, V _I (see Note 1) Input current range	\ldots -1.2 V to 7 V
Voltage range applied to any output in the disabled or power-off state	
Voltage range applied to any output in the high state	–0.5 V to V _{CC}
Current into any output in the low state: SN54F244	96 mA
	128 mA
Operating free-air temperature range: SN54F244	–55°C to 125°C
SN74F244	0°C to 70°C
Storage temperature range	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input voltage ratings may be exceeded provided the input current ratings are observed.



recommended operating conditions

		SN54F244			S	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage	0.8				0.8	V	
Iк	Input clamp current	-18				-18	mA	
ЮН	High-level output current		- 12		– 12		- 15	mA
IOL	Low-level output current	48				64	mA	
Тд	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEO	SN54F244 SI				SN74F244		4	
PARAMETER	IES	TEST CONDITIONS		түр†	MAX	MIN	TYP [†]	MAX	UNIT
VIK	V _{CC} = 4.5 V,	lj = -18 mA			-1.2			-1.2	V
		$I_{OH} = -3 \text{ mA}$	2.4	3.3		2.4	3.3		
Vau	$V_{CC} = 4.5 V$	I _{OH} = - 12 mA	2	3.2					V
∨он		I _{OH} = - 15 mA				2	3.1		v
	V _{CC} = 4.75 V,	$I_{OH} = -3 \text{ mA}$				2.7			
Ve	V _{CC} = 4.5 V	I _{OL} = 48 mA		0.38	0.55				V
VOL	VCC = 4.3 V	I _{OL} = 64 mA					0.42	0.55	v
IOZH	V _{CC} = 5.5 V,	$V_{O} = 2.7 V$			50			50	μΑ
I _{OZL}	V _{CC} = 5.5 V,	$V_{O} = 0.5 V$			-50			-50	μΑ
lj	V _{CC} = 5.5 V,	$V_{I} = 7 V$			0.1			0.1	mA
ΙΗ	V _{CC} = 5.5 V,	VI = 2.7 V			20			20	μΑ
OE					- 1			- 1	mA
I _{IL} Any A	$V_{CC} = 5.5 V,$	V _I = 0.5 V			- 1.6			- 1.6	ША
IOS [‡]	V _{CC} = 5.5 V,	$V_{O} = 0$	-100		-225	-100		-225	mA
	Outputs high	Outputs high		40	60		40	60	
ICC	$V_{CC} = 5.5 V,$ Outputs open	Outputs low		60	90		60	90	mA
		Outputs disabled		60	90		60	90	

† All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ Not more than one output should be shorted at a time, and the duration of the short circuit should not exceed one second.



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switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	CI RI	CC = 5 V L = 50 p L = 500 9 L = 500 9 L = 25°C	F, Ω,	CL RL	= 50 pF = 500 Ω			UNIT
				′ F244		SN54	F244	SN74F244		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
^t PLH	A	V	1.7	3.6	5.2	2	6.5	1.7	6.2	ns
^t PHL		ř	1.7	3.6	5.2	2	7	1.7	6.5	115
^t PZH	OE	V	1.2	3.9	5.7	2	7	1.2	6.7	ns
^t PZL		Ŷ	1.2	5	7	2	8.5	1.2	8	115
^t PHZ	OE	v	1.2	4.1	6	2	7	1.2	7	ns
^t PLZ	σL	1	1.2	4.1	6	2	7.5	1.2	7	115

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Load circuits and waveforms are shown in Section 1.



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